# $R$ eal space $n$ ite di erence $m$ ethod for conductance calculations 

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#### Abstract

W e present a generalm ethod for calculating coherent electronic transport in quantum $w$ ires and tunnel junctions. It is based upon a realspace high order nite di erence representation of the single particle $H$ am iltonian and wave functions. Landauer's form ula is used to express the conductance as a scattering problem. D ividing space into a scattering region and left and right ideal electrode regions, th is problem is solved by wave function $m$ atching (W FM) in the boundary zones connecting these regions. The $m$ ethod is tested on a modeltunnel junction and applied to sodium atom ic $w$ ires. In particular, we show that using a high order nite di erence approxim ation of the kinetic energy operator leads to a high accuracy at $m$ oderate com putational costs.


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## I. INTRODUCTION

The progress in experim entalcontrolon the nanom eter scale has enabled studies of electronic transport in quantum wires of atom ic dim ensions ${ }^{\frac{1}{1}} \mathrm{~T}$ he transport properties of such system s have to be understood on the basis of their atom ic structure. This notion has generated a large e ort in recent years to calculate the conductance of quantum wires from rst principles. Several di erent approaches have been form ulated, which have a com $m$ on basis in the Landauer-Buttiker approach to express the conductance of a coherent system in term s of a quantum $m$ echanicalscattering problem $\frac{2}{2}$ In such calculations the quantum wire consists of a scattering region of nite size, sandw iched betw een tw o sem i-in nite leads that are considered to be idealballistic wires. Sem i-em pirical tight-binding $m$ odels have been exploited to solve this problem $3,4,5,6$ A im ing at a better description of the electronic structure, several current approaches rely upon density functional theory (DFT).

The $m$ ain di erences betw een these approaches lie in the approxim ations that are used to describe the atom ic structure of the leads and in the techniques that are used to solve the scattering problem. In pioneering work, jellium (i.e. free electron) electrodes have been used to describe the leads and the scattering wave functions have been obtained by a transfer $m$ atrix $m$ ethod ${ }^{7}$ or by solving the Lippm an-Schw inger equation ${ }^{8,9}$ A transfer $m$ atrix $m$ ethod has also been used taking into account the full atom ic structure of the leads at the D FT level ${ }^{10,11}$ A ltematively, the conductance can be calculated using a $G$ reen function approach $w$ thout calculating the scattering $w$ ave functions explicitly 12 Several im plem entations of this approach have been form ulated that use a localized basis set to form a representation of the scattering problem. These im plem entations $m$ ainly di er in the kind of basis set used, e.g. Gaussian or num erical atom ic orbitals, or wavelets. $13,14,15,16,17,18,19$ A n em bedded $G$ reen function approach has been applied using a delocalized basis set of augm ented plane w aves ${ }^{20}$

In this paper we present a technique for solving the
scattering problem of a quantum $w$ ire $w$ thout the use of a basis set. Instead, potentials and wave functions are represented on a uniform real space grid and di erential operators are approxim ated by a nite di erence approxim ation (FDA). P revious im plem entations of this idea have used a sim ple rst orderFDA ${ }^{21,22,23,24}$ In that case the grid has to be relatively ne in order to obtain su ciently converged results. This hinders the application to large system s because of the com putational costs involved in using ne grids. H ow ever, in ground state (D FT) electronic structure calculations high order FDA's have been shown to markedly increase the eciency of real space grid techniques by enabling the use of coarse grids ${ }^{25,26,27}$ In this paper we dem onstrate that high order FDA's m ake it possible to solve the scattering problem much m ore e ciently.

The $m$ ethod we propose for calculating the conductance of a quantum w ire is based upon wave function $m$ atching (W FM) in the boundary zones connecting the leads and the scattering region 28 Unlike transfer $m$ atrix m ethods, how ever, it does not require the explicit calculation of $w$ ave functions in the scattering region 7,10,11 It does not require the explicit calculation of $G$ reen functions either, $12,13,14,15,16,17,18,19,20$ which enables us to solve the scattering problem at real, instead of com plex, energies ${ }^{29}$ O urm ethod can be classi ed as an $O(\mathbb{N})$ technique, since the com puting costs are determ ined by the size of the scattering region w ith which they scale linearly. A related technique that uses a linearized mu n tin onbital basis set, has been applied to calculate the electronic transport in layered $m$ agnetic $m$ aterials 30,31 A though the form alism presented here can be extended to the non-equilibrium situation, we consider in this paper the linear response regim e only.

This paper is organized as follows. In Sec. The $m$ ain ingredients of our com putational $m$ ethod are explained, where the com putationaldetails can be found in appendix $A$. The accuracy and convergence properties of the $m$ ethod are veri ed on $m$ odel tunnel junctions in Sec. IIIA. T he application to a m ore com plex system, which consists of a sodium atom ic wire, is discussed in

Sec.IIIB. A sum m ary is given in Sec.IV.

## II. COMPUTATIONALMETHOD

W ithin the Landauer-Buttiker approach the conductance $G$ of a quantum wire is expressed in term $s$ of the total transm ission T (E )

$$
\begin{equation*}
\mathrm{G}=\frac{\mathrm{e}^{2}}{\sim} \mathrm{~T}(\mathbb{E}) ; \tag{1}
\end{equation*}
$$

assum ing spin degeneracy ${ }^{2}$ T ( $\mathbb{E}$ ) can be obtained by solving the quantum $m$ echanical scattering problem at the xed energy E. Eq. (1) is valid in the linear response regim $e$, where $T$ ( $E$ ) needs to be evaluated at the Ferm ienergy $E=E_{F}$. O ur quantum $W$ ire is de ned as a system consisting of a nite scattering region that is connected left and right to sem i-in nite leads. The latter are supposed to be 'ideal' w ires, which can be described by a periodic potential along the wire direction. In the scattering region the potential can have any shape. W e consider two cases that can be treated by essentially the sam e technique. In the rst case the system has a nite cross-section perpendicular to the wire direction, w hereas in the second case the system is periodic penpendicular to the w ire. T he latter case also covers planar interfaces and tunnel junctions.

In order to solve the scattering problem we generalize a $m$ ethod form ulated by A ndo ${ }^{28} \mathrm{H}$ ere one basically solves a single particle Schrodinger equation directly at a xed energy $E$ in two steps. In the rst step one obtains the $m$ odes of the ideal leads. Subsequently the $w$ ave functions for the scattering region are constructed such, that they are properly $m$ atched to the solutions in the leads. $W$ e use a real space nite di erence $m$ ethod to represent the Schrodinger equation. In the follow ing three subsections we will introduce this representation and discuss the steps required to solve the scattering problem.

## A. Fin ite di erence approxim ation

W e start from a single particle equation of the general form

$$
\begin{equation*}
\text { E } \quad V(r)+\frac{\sim^{2}}{2 m} r^{2} \quad(r)=0 ; \tag{2}
\end{equation*}
$$

which represents the Schrodinger equation of a single particle in a potential V. A ltematively, within the DFT scheme it represents the K ohn-Sham equation $w$ ith V the totale ective potential. $W$ e put the wave function and the potentialV on a equidistant grid in realspace $r=\left(\mathrm{x}_{\mathrm{j}} ; \mathrm{y}_{\mathrm{k}} ; \mathrm{z}_{\mathrm{l}}\right)$, where $\mathrm{x}_{\mathrm{j}}=\mathrm{x}_{0}+j \mathrm{~h}_{\mathrm{x}} ; \mathrm{y}_{\mathrm{k}}=\mathrm{y}_{0}+\mathrm{kh} \mathrm{h}_{\mathrm{y}} ; \mathrm{z}_{\mathrm{l}}=$ $z_{0}+\mathrm{lh}_{\mathrm{z}}$ and $\mathrm{h}_{\mathrm{x}} ; \mathrm{h}_{\mathrm{y}} ; \mathrm{h}_{\mathrm{z}}$ are the grid spacings in $\mathrm{x} ; \mathrm{y}$ and z directions, respectively. Follow ing R efs. 25 , 26 we replace the kinetic energy operator in Eq. (2) by a high order
(a)

(b)


FIG. 1: (C olor online) (a) The system is divided into cells indicated by an index i. The cells have $L \quad W_{y} \quad W_{z}$ grid points in the xiy and $z$ directions, respectively. $i$ is the supervector that contains the w ave function values on all grid points in cell i. (b) $\mathrm{H}_{i}$ is the H am ilton m atrix connecting grid points $w$ ith in cell $i$; the $B-m$ atrix connects grid points betw een neighboring cells and is independent of $i$.

FDA. For the x part this gives

$$
\begin{equation*}
\frac{@^{2}\left(x_{j} ; y_{k} ; z_{1}\right)}{@ x^{2}} \frac{1}{h_{x}^{2}}{ }_{n=N}^{X^{N}} c_{n}\left(x_{j+n} ; y_{k} ; z_{1}\right) ; \tag{3}
\end{equation*}
$$

$w$ ith sim ilar expressions for the $y$ and $z$ parts. Expressions for the coe cients $c_{n}$ for various values of $N$ are tabulated in Ref. 26. The sim plest approxim ation in Eq. (3) $\left(\mathbb{N}=1\right.$, where $c_{1}=c_{1}=1$ and $c_{0}=2$ ) reduces Eq. (2) to the well-known sim ple nite di erence representation of the Schrodinger equation $12,21,22,23,24 \mathrm{How}-$ ever, we will dem onstrate that the scattering problem can be solved $m$ uch $m$ ore e ciently using higher order FDA'swith $N=4-6$.

In a FDA the Schrodinger equation ofEq. (2) becom es

$$
\begin{array}{r}
\left(E \quad V_{j ; k ; 1}\right) \quad j ; k ; 1+X_{n=N}^{N} \quad t_{n}^{X} \quad j+n ; k ; 1+t_{n}^{Y} \quad j ; k+n ; 1+ \\
\\
t_{n}^{Z} \quad j ; k ; l+n=0 ;(4)
\end{array}
$$

where $V$; $j ; k ; 1$ is a short-hand notation forV; ( $\mathrm{x}_{\mathrm{j}} ; \mathrm{Y}_{\mathrm{k}} ; \mathrm{z}_{1}$ ) and $\mathrm{t}_{\mathrm{n}}^{\mathrm{x} ; i \mathrm{z}}=\sim^{2}=2 \mathrm{~m} \mathrm{~h}_{\mathrm{x} ; \mathrm{y} ; \mathrm{z}}^{2} \quad \mathrm{G}$. In order to m ake a connection to A ndo's form alism ${ }^{28}$ we divide the $w$ ire into cells of dim ension $a_{x} \quad a_{y} \quad a_{z}$. The direction of the $w$ ire is given by the $x$-axis. T he num ber of grid points in a cell is $L=a_{x}=h_{x}, W_{y}=a_{y}=h_{y}, W_{z}=a_{z}=h_{z}$ for the $x, y$ and $z$ directions respectively. W e w ish to distinguish betw een tw o di erent cases. In the rst case the wire has a nite cross-section in the yz plane. In the second case the w ire has an in nite cross-section, but it has a periodic potential in the $y z$ plane, i.e. $V_{j ; k+w_{y ; 1}}=V_{j ; k ; l+w}=V_{j ; k ; 1}$.

In both cases the (unit) cell in the yz plane is described by $W_{y} \quad W_{z}$ grid points.

The values $j ; k ; 1$ where the indices $j ; k ; 1$ correspond to a single celli iare grouped into a supervector i. The idea is shown in F ig. 1. This supervector has the dim ension $\mathrm{N}_{\mathrm{rs}}=\mathrm{L}$ WI W, which is the totalnum ber of realspace grid points in a cell. If we let i denote the position of the cell along the w ire then Eq. (4) can then be rew ritten as

$$
\begin{equation*}
\text { (E I } \left.\quad H_{i}\right)_{i}+B \quad i 1+B^{y} \quad i+1=0 ; \tag{5}
\end{equation*}
$$

for $i=1 ;::: ; 1$. Here $I$ is the $N_{r s} \quad N_{r s}$ identity $m$ atrix. The $m$ atrix elem ents of the $N_{r s} \quad N_{r s} m$ atrices $H_{i}$ and $B$ can be derived straightforw ardly from Eq. (4). The expressions are given in appendix A 1, both for a $w$ ire that is nite and for a w ire that is periodic in the yz plane. For the latter $\mathrm{H}_{\mathrm{i}}=\mathrm{H}_{\mathrm{i}}\left(\mathrm{k}_{\mathrm{k}}\right)$, where $\mathrm{k}_{\mathrm{k}}$ is a wave vector in the two-dim ensional B rillouin zone. In the follow ing this notation is suppressed.

Eq. (5) has the form ofa nearest neighbor tight-binding equation, expressed in term $s$ of vectors/m atrices of di$m$ ension $N_{r s}$. This form enables us to use A ndo's technique to solve the scattering problem ${ }^{28} \mathrm{~N}$ ote however that the $m$ atrices $B ; B^{y}$ in $E q$. (4) are singular, see Eq. A3), which requires a generalization of this technique.

## B . Ideal w ire

A $n$ idealw ire is de ned by a potential that is periodic in the direction of the $w$ ire, i.e. $V\left(x_{j}+a_{x} ; y_{k} ; z_{1}\right)=$ $V\left(x_{j} ; y_{k} ; z_{l}\right)$ or $V_{j+L ; k ; 1}=V_{j ; k ; 1}$. Since the potential is the sam $e$ in each cell, the $m$ atrix $H_{i}=H$ in Eq. (5) is independent of the cell position i. In a periodic system the vectors in subsequent cells are related by the B loch condition

$$
\begin{equation*}
i=i+1 ; \tag{6}
\end{equation*}
$$

$w h e r e=e^{i k_{x} a_{x}} w$ ith $k_{x}$ real for propagating $w a v e s$ and com plex for evanescent (grow ing or decaying) waves. C om bining Eqs. (5) and (6) one then obtains the follow ing generalized eigenvalue problem

| EI | $H$ | $B$ | $B^{Y}$ | 0 | i | $=0:$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |

Form ally, the dim ension of this problem is $2 \mathrm{~N}_{\mathrm{rs}}$. There are a num ber oftrivialsolutions, how ever, since $B ; B^{y}$ are singularm atrices. In appendix A 2 it is show $n$ how reduce the problem to its 2 N W W non-trivialsolutions.
$T$ he non-trivialsolutions ofEq. (7) can be divided into tw o classes. The rst class com prises B loch w aves propagating to the right and evanescent $w$ aves decaying to the right; the corresponding eigenvalues are denoted by
(+ ). The second class com prises B loch w aves propagating to the left or evanescent waves decaying to the left; the eigenvalues are denoted by ( ). The eigenvalues of
the propagating waves have $j() j=1$ and for evanescent waves j ( ) j 7 1. The evanescent states come in pairs, since it is easy to show that for every solution (+) there is a corresponding solution ()$=1=(+)$. It can be show $n$ that the propagating states also com e in pairs, i.e. for every right propagating wave ( + ) there is a left propagating wave ( ) ${ }^{32}$

It $m$ akes sense to keep only those evanescent $w$ aves for which $1=<j j<$, where is a su ciently large num ber. States with $j$ joutside this interval are extrem ely fast decaying or grow ing. Such states are not im portant in $m$ atching an ideal $w$ ire to a scattering region. Typical of nite di erence schem es there are also nonphysical solutions to Eq. (7), which are related to socalled parasitic m odes ${ }^{33,34}$ These are easily recognized and discarded since their $j$ j's are either extrem ely sm all or large and thus falloutside the selected interval. M oreover, these $j j$ s are very sensitive to the grid spacing and rapidly go to 0 or 1 if the grid spacing is decreased.

A fter ltering out the physical and useful solutions Eq. (7) we end up with M pairs of solutions $m() ; m=$ 1;:::;M, where usually $\mathrm{M} \quad \mathrm{N}_{\text {rs }}$. We construct the norm alized vectors $u_{m}$ ( ) from the rst $N_{r s}$ elem ents of the eigenvectors ofEq. 7) and form the $N_{r s} M m$ atrices

$$
\begin{equation*}
U()=\left(u_{1}() \quad M(u)\right): \tag{8}
\end{equation*}
$$

C hoosing the cell $i=0$ as the origin, one then w rites the general solution 0 in this cell as a linear com bination of these right- and left going $m$ odes

$$
\begin{equation*}
0=0(+)+0() \tag{9}
\end{equation*}
$$

where

$$
\begin{equation*}
o()=U() a()=\mathrm{X}_{\mathrm{m}=1}^{\mathrm{X}_{\mathrm{M}}} \mathrm{u}_{\mathrm{m}}() a_{\mathrm{n}}() ; \tag{10}
\end{equation*}
$$

with a ( ) vectors of arbitrary coe cients of dim ension M .

De ning the $M \quad M$ diagonal eigenvalue $m$ atrices by

$$
\begin{equation*}
\left(\quad \left(\quad h_{\mathrm{m}}=\mathrm{nm} \mathrm{~m}() ;\right.\right. \tag{11}
\end{equation*}
$$

and using the B loch condition ofEq. (6), the solution in the other unit cells then can be expressed in a com pact form

$$
\begin{equation*}
i=U(+)^{i}(+) a(+)+U()^{i}() a(): \tag{12}
\end{equation*}
$$

In order to apply A ndo's form alism 28 it is advantageous to slightly rew rite this. W e de ne the $\mathrm{N}_{\text {rs }} \quad \mathrm{N}_{\text {rs }}$ $m$ atrices F ( ) and ( ) by

$$
\begin{align*}
& F() U()=U()()  \tag{13}\\
& E() U()=U()^{1}(): \tag{14}
\end{align*}
$$

N ote that $\left.\sum^{( }\right) \not F^{1}()$ since the $N_{r s} \quad M \quad m$ atrices U ( ) are not square (typically M $\quad \mathrm{N}_{\text {rs }}$ ). This presents


F IG . 2: (C olor online) (a) Schem atic representation of quantum w ire. T he left ( $L$ ) and right ( R ) leads are idealw ires that span the cells $i=1 ;::: ; 0$ and $i=S+1 ;::: ; 1$, respectively. The scattering region spans cells $i=1 ;::: ; S$. (b) $T$ he reduced problem spans the cells $i=0 ;:: ; S+1$, see Eq. 26].
no problem, how ever, and explicit expressions for the matrices ; F are given in appendix A 3. They allow Eq. (12) to be rew ritten in recursive form

$$
\begin{align*}
& i+1=F(+) i(+)+F()_{i}() ;  \tag{15}\\
& i 1=F(+)_{i}(+)+F()_{i}() ; \tag{16}
\end{align*}
$$

either of which allow s one to construct the full solution for the ideal w ire, once the boundary values are set, cf. Eq. (9) .

## C. Scattering problem

In a non-ideal quantum w ire the potential is not periodic, which $m$ eans that we have to solve the Schrodinger equation of Eq. (5) w ith $\mathrm{H}_{\mathrm{i}}$ depending upon the position i along the wire. T he non-ideal region (the scattering region) is supposed to be nite, spanning the cells $i=1 ;::: ; S^{35} T$ he left and right leads are ideal w ires, spanning the cells $i=1$;:::;0 and $i=S+1 ;::: ; 1$, respectively. In the ideal $w$ ires $H_{i}$ does not depend on the position of the cell. H ow ever, the left lead can be di erent from the right one, so we use the subscript $L(R)$ to denote the form er (latter), i.e. $H_{i}=H_{L}$; i<1 and $H_{i}=H_{R}$; i>S.A schem atic picture of the structure is shown in F ig. (2) (a). W e solve Eq. (5) over the whole space, $i=1 ; 1, m a k i n g$ use of the ideal wire solutions of the previous section to reduce the problem to essentially the scattering region only, see Fig. (2)(b).

For the solution in the left lead the recursion relation of Eq. (16) can be used. This gives for the cell $i=1$

$$
\begin{align*}
1 & =e_{L}(+) 0(+)+e_{L}() 0() \\
& \left.=E_{L}(+) e_{L}()\right] 0(+)+e_{L}() 0 ; \tag{17}
\end{align*}
$$

using Eq. (9). The vector 0 (+ ) describes a w ave com ing in from the left. In a scattering problem this vector xes the boundary condition. Eq. (17) allows Eq. (5) for $i=0$ to be w ritten as

$$
\begin{equation*}
\text { (EI } \left.\mathbb{P}_{0}\right){ }_{0}+B^{Y}{ }_{1}=Q \quad 0(+) \text {; } \tag{18}
\end{equation*}
$$

where

$$
\begin{align*}
& \mathbb{P}_{0}=H_{L} \quad B \mathbb{P}_{L}(\quad) \\
& \left.Q=B \mathbb{E}_{L}(\quad) \quad e_{L}(+)\right]: \tag{19}
\end{align*}
$$

For the solution in the right lead we use the recursion relation of Eq. (15), which gives for the cell $i=S+2$

$$
\begin{equation*}
s+2=F_{R}(+) \quad s+1(+): \tag{20}
\end{equation*}
$$

H ere we have assum ed that in the right lead we have only a right going wave, which corresponds to the transm itted wave. Eq. (20) allow s Eq. (5) for $i=S+1$ to be written as

$$
\begin{equation*}
\text { (EI } \left.\mathbb{P}_{s+1}\right) \quad s+1+B \quad s=0 ; \tag{21}
\end{equation*}
$$

where

$$
\begin{equation*}
\mathbb{P}_{\mathrm{S}+1}=\mathrm{H}_{\mathrm{R}} \quad \mathrm{~B}^{\mathrm{Y}} \mathrm{~F}_{\mathrm{R}}(+): \tag{22}
\end{equation*}
$$

Eqs. (19) and (22) take care of the coupling of the scattering region to the left and right leads. Eq. (5) for $i=1 ;::: ; S$ plus Eqs. (18) and (21) form a com plete set of equations from which the vectors $i ; i=0 ;::: ; S+1$ can be determ ined describing the w aves in the scattering region.

The scattering re ection and transm ission coe cients can be deduced from the am plitudes im m ediately left and right of the scattering region, i.e. 0 and $s+1$. If we let the incom ing $w$ ave consist of one speci cm ode, $0(+)=$ $u_{L ; n}$, i.e. $a_{m}(+)=m n$ in Eq. (9), then the generalized re ection and transm ission probability am plitudes $r_{n} 0_{n}$ and $t_{n} 0_{n}$ are de ned by

$$
\begin{align*}
& O()=\sum_{n^{0}=1}^{X_{L}} u_{L ; n^{0}}()_{n_{n} 0_{n}} \\
& \text { 禁 }{ }^{\text {R }} \\
& s+1(+)=u_{n^{0}=1} u_{R ; n^{0}}(+) t_{n} 0_{n}: \tag{23}
\end{align*}
$$

$N$ ote that at this stage we include all evanescent and propagating $m$ odes since these form a com plete set to represent the states in the leads. W e assum e the lead states to be am plitude nom alized.

The re ection and transm ission probability am plitudes $r_{n} 0_{n}$ and $t_{n} o_{n}$ between all possible $m$ odes form a $M_{L}$
$M_{L} m$ atrix $R$ and $a M_{R} \quad M_{L} m$ atrix $T$, respectively. A 11 elem ents of these $m$ atrioes can be found in one go by de ning a $N_{r s} \quad M_{L} m$ atrix of all possible incom ing m odes, i.e.

$$
\begin{equation*}
\mathrm{C}_{0}(+)=\mathrm{U}_{\mathrm{L}}(+): \tag{24}
\end{equation*}
$$

A nalogous to Eq. (23) one then has

$$
\begin{align*}
& C_{0}()=C_{0} \quad C_{0}(+)=U_{L}(\quad) R \\
& C_{S+1}(+)=C_{S+1}=U_{R}(+) T: \tag{25}
\end{align*}
$$

Eqs. (18), (5) and (21) then becom e
8
$<\quad\left(E I \quad P_{0}\right) C_{0}+B^{y} C_{1}=Q U_{L}(+)$
(EI $\left.\quad H_{i}\right) C_{i}+B C_{i 1}+B^{y} C_{i+1}=0$
(EI $\left.\mathbb{P}_{S+1}\right) C_{S+1}+B C_{S}=0$;
$i=1 ;::: ;$ S. Solving this set of equations for $C_{i} ; i=$ $0 ;::: ; S+1$ gives all possible waves. From Eq. (25) one can then extract the generalized re ection and transm ission $m$ atrioes $R$ and $T$. An e cient technique for solving the equations is discussed in appendix A 4.

In order to calculate the total transm ission one has to select the transm ission $m$ atrix elem ents that refer to propagating $m$ odes and discard the ones that refer to evanescent m odes. This is easy, since the propagating m odes have $j$ j= 1, see the discussion above Eq. (8). $T$ he total transm ission of Eq . (1) is then given by

$$
\begin{equation*}
T(E)={ }_{n=1 ; n^{0}=1}^{m^{m} X^{m}{ }^{m}} \frac{V_{R ; n} n^{0}}{V_{L}} \operatorname{t}_{n} 0_{n} J^{2} ; \tag{27}
\end{equation*}
$$

$w$ here $v_{R ; n}{ }^{0}$ and $v_{L ; n}$ are the velocities in the $x$-direction of the right propagating $w$ aves in the right and left lead in the $m$ odes $n^{0}$ and $n$, respectively, and $m_{L} ; m_{R}$ are the num ber of such $m$ odes. Introducing the velocities results from ux nom alizing the $m$ odes, which is required by current conservation ${ }^{12}$ The velocities are given by the expression

$$
\begin{equation*}
\mathrm{v}_{\mathrm{n}}=\frac{2 \mathrm{a}_{\mathrm{x}}}{\sim} \operatorname{Im} \quad \mathrm{n}_{\mathrm{n}}^{\mathrm{y}} \mathrm{~B}^{\mathrm{y}} \mathrm{u}_{\mathrm{n}} ; \tag{28}
\end{equation*}
$$

where subscripts $L(R)$ need to be added for the left (right) leads. Eq. (28) is derived in appendix A 5. The sign of the calculated velocities is used to distinguish right from left propagating $m$ odes.
D. C om putational costs

O ur computational $m$ ethod can be sum $m$ arized as follow s. First, Eq. (7) is solved in its reduced form, Eq. A 8), to obtain the modes for both leads. The computing costs of this step scale as $N_{\text {id }}^{3}$, where $\mathrm{N}_{\text {id }}=\max (2 \mathrm{~N} ; \mathrm{L} \mathrm{N})$ W W, see appendix A 2. $T$ hese costs are sm allcom pared to the costs of solving the scattering problem. T he next step involves the selection of the physically relevant $m$ odes $u_{m}$ and separate them into left (+) and right ( ) going m odes. T he velocities are calculated using Eq. (28) and are used to distinguish left from right propagating states. E vanescent states are classi ed as grow ing (+ ) or decaying ( ) on account of their eigenvalue. Subsequently, the F $m$ atrices are constructed, Eq. (13), and the $m$ atrix elem ents that de ne


F IG . 3: (C olor online) The potential of Eq. 29. in the $x y-$ plane for the cases (a) $V_{0}=0$ and (b) $V_{0}=V_{1}$.
the boundary conditions on the scattering region are set, see Eqs. (19) and (22). T he com puting costs of these steps are $m$ inor.
$T$ he transm ission $m$ atrix $T$ is obtained by solving Eq. (26) using the algorithm of appendix (4. This is the $m$ ost tim e consum ing step. It scales as $S$, where $N_{r s}=L$ Wु is the num ber of grid points in the unit cell and $S$ is the num ber of unit cells in the scattering region. N ote that the scaling is linear with respect to the size $S$ of the scattering region, which $m$ eans that th is algorithm can be classi ed as $O(\mathbb{N})$. Finally, the total transm ission and the conductance can be obtained from Eqs. (27) and (1).

## III. RESULTS

## A. N um erical tests

In order to test the accuracy ofourm ethod we consider a system described by the $m$ odel potential

$$
\begin{align*}
V(r) & =V_{0}[\cos (2 x=a)+\cos (2 y=a)+\cos (2 \quad z=a)] \\
& +\frac{V_{1}}{\cosh ^{2}(x=a)}: \tag{29}
\end{align*}
$$

The $V_{0}$ term describes an ideal $w$ ire by a simple three dim ensional periodic potential $w$ ith periods $\mathrm{a}_{\mathrm{x}}=\mathrm{a}_{\mathrm{y}}=$ $a_{z}=a . T$ he $V_{1}$ term describes a barrier in the propagation direction and is a sim plem odel for a tunnel junction. T he potential is plotted in F ig. 3. W e solve the scattering problem for this system num erically in three dim ensions by the $m$ ethod outlined in Sec. Ti. O ur results can be veri ed, how ever, since this potential is in fact separable and lim iting cases can be solved analytically. T he solutions in the $y$ - and $z$-directions are $M$ athieu functions. ${ }^{36}$ If $\mathrm{V}_{1}=0$ then the solutions in the x -direction are also M athieu functions. If $\mathrm{V}_{1} \in 0$ but $\mathrm{V}_{0}=0$ the scattering problem can be solved analytically ${ }^{37} \mathrm{~F}$ inally, if $\mathrm{V}_{1} \in 0$ and $V_{0} \in 0$ the solution in the $x$ direction can be obtained using the separability of the potential and a standard num ericalsolver for the resulting ordinary di erentialequation in the $x$-direction ${ }^{38}$ In the follow ing the latter $w$ ill be called the \exact" num erical solution.


FIG.4: The calculated wave num ber $k_{x}$ (in units of $=a$ ) as function of the energy $E$ (in units of $V_{0}$ ) for an ideal w ire. $T$ he points indicate the num erical results obtained $w$ ith $L^{\prime} ; W_{y} ; W_{x}=8$ and $N=4$. The solid line indicates the exact solution of the $M$ athieu problem .

As a rst test we consider an ideal wire, i.e. $\mathrm{V}_{1}=0$ in Eq. (29). The potential is separable and we can w rite the energy as $\mathrm{E}\left(\mathrm{k}_{\mathrm{x}} ; \mathrm{k}_{\mathrm{y}} ; \mathrm{k}_{\mathrm{z}}\right)=\mathrm{n}_{\mathrm{x}}\left(\mathrm{k}_{\mathrm{x}}\right)+\mathrm{n}_{\mathrm{y}}\left(\mathrm{k}_{\mathrm{y}}\right)+\mathrm{n}_{\mathrm{z}}\left(\mathrm{k}_{\mathrm{z}}\right)$, where ${ }_{n}(k) ; k=\quad=a ;:: ;{ }^{2}=\mathrm{a}=0 ; 1 ;::$ : are the eigenvalues of the $M$ athieu problem 36 Fig . 4 show $S$ part of the analytical band structure for ( $k_{x} ; \mathrm{k}_{\mathrm{y}} ; \mathrm{k}_{\mathrm{z}}$ ) = $(0 ; 0 ; 0)!(=a ; 0 ; 0)$. It essentially consists ofa supenposition of one-dim ensional band structures $n_{x}\left(k_{\mathrm{x}}\right) \circ$ set by energies $n_{y}(0)+n_{z}(0) ; n_{y} ; n_{z}=0 ; 1 ;:::$
$T$ he num erical band structure is obtained by solving Eq. (7) in its reduced form, Eq. (A). To obtain the results shown in F ig. 4 we set $\mathrm{k}_{\mathrm{k}}=\left(\mathrm{k}_{\mathrm{y}} ; \mathrm{k}_{\mathrm{z}}\right)=(0 ; 0)$, cf. Eq. A4, and determ ine the eigenvalues in Eq. 7) as a function ofE. For the propagating states one can w rite
$=\exp \left(\mathrm{i}_{\mathrm{x}} \mathrm{a}\right)$. P lotting the calculated w ave num ber $\mathrm{k}_{\mathrm{x}}$ as function of the energy $E$ then allow s to com pare the results w th the analytical band structure. T he num erical results shown in F ig. 4 are obtained using a grid of $\mathrm{L} ; \mathrm{W}_{\mathrm{y}} ; \mathrm{W}_{\mathrm{z}}=8$ points per period and aFDA w th $\mathrm{N}=4$. A though this grid is relatively coarse, we obtain a relative accuracy on $k_{x}$ of $10^{3}$.
$T$ his perhaps surprising accuracy is entirely due to the use of a high order FD A. To illustrate this, Table $\mathbb{1}$ show s the convergence ofk $k_{x}$ at a num ber ofenergies $E$ as a function of the order $N$ of the FDA and the number of grid points L. These particular results were obtained using the separability of the potential and solving the problem num erically in the $x$-direction only, while using analytical solutions for the y -and z -directions. For $\mathrm{N}=6$ and $\mathrm{L}=14$ the results are converged to w th in $10^{7}$ of the exact result. This is in shanp contrast to the results obtained w ith a simple rst order $(\mathbb{N}=1)$ FDA, where a sim ilar convergence can only be obtained at the cost of using tw o orders of $m$ agnitude $m$ ore grid points. U sing such a large num ber of grid points in three dim ensions is entirely prohibitive because of the high com putational

TABLE I: $k_{x}(E)$ (in units of $=a$ ) at values of $E$ (in units of $\mathrm{V}_{0}$ ) in the low est two bands and in the rst band gap of Fig. 4; in the band gap we nd $k_{x}=1+i_{x}$.

| N | L | $\mathrm{k}_{\mathrm{x}}(0: 6)$ | $\mathrm{k}_{\mathrm{x}}(1: 0)$ | $\mathrm{x}(0: 3)$ |
| :---: | :---: | :---: | :---: | :---: |
| 1 | 7 | 0.694906 | 0.283091 | 0.283549 |
|  | 10 | 0.608958 | 0.322712 | 0.304238 |
|  | 14 | 0.571387 | 0.342011 | 0.312259 |
|  | 100 | 0.533341 | 0.359187 | 0.319658 |
|  | 1000 | 0.533084 | 0.359425 | 0.319688 |
| 4 | 5 | 0.544347 | 0.355049 | 0.317777 |
|  | 7 | 0.533962 | 0.358927 | 0.319476 |
|  | 10 | 0.533149 | 0.359389 | 0.319673 |
|  | 14 | 0.533087 | 0.359425 | 0.319687 |
| 6 | 7 | 0.533228 | 0.359337 | 0.319658 |
|  | 10 | 0.533086 | 0.359425 | 0.319688 |
|  | 14 | 0.533082 | 0.359428 | 0.319688 |
| Exact |  | 0.533082 | 0.359428 | 0.319688 |

costs involved. For exam ple, aim ing at a m oderate accuracy of $10^{2}$, it is observed that for $N=4$ and $L=5$ the results are $m$ arkedly better than for $N=1$ and $L=14$. Yet in a three dim ensional calculation, w thout using the separability of the potential, the com puting tim e required for the latter is two orders of $m$ agnitude larger than for the form er. It $m$ eans that in order to solve a generalnonseparable three dim ensionalproblem w ith reasonable accuracy and com putational costs, it is vital to use a high order FDA.
$N$ ext we consider the scattering problem and calculate the total transm ission for the case where $V_{1} \in 0$. The size of the scattering region is set to S a and outside this region the scattering potential (the last term ofE q. (29)) is set to zero. W ith $S=6$ the results are extrem ely well converged. A s an exam ple we have calculated the transm ission at norm al incidence, i.e. $\mathrm{k}_{\mathrm{k}}=\left(\mathrm{k}_{\mathrm{y}} ; \mathrm{k}_{\mathrm{z}}\right)=(0 ; 0)$. The crosses $m$ arked $V_{0}=0$ in F ig. 5 represent the nu$m$ erical results for the transm ission of the corresponding potential, obtained $w$ ith $a L_{i} ; W_{y} ; W_{z}=8$ grid and $a$ $\mathrm{N}=4 \mathrm{FDA} . \mathrm{Th}$ is scattering problem can also be solved analytically, 37 and the analytical and num erical transm ission probabilities agree w ithin $10^{4}$.

Fig. 5 also show s the transm ission for the case where $V_{0}=V_{1}$ as calculated num erically using the sam e param eters as before, i.e. $S=6 ; L_{y} ; W_{y} ; W_{z}=8 ; N=4$. This scattering problem can only be solved sem i-analytically; $M$ athieu solutions are used in $y$ - and $z$-directions, and the (ordinary) di erential equation for the $x$-direction is solved \exactly" using an accurate standard num erical solver ${ }^{38}$ A gain the \exact" and num erical transm ission probabilities agree w ithin $10^{4}$. C om pared to the $V_{0}=0$ case it is observed that the in uence of the periodic potential of the leads upon the transm ission is large. For $\mathrm{V}_{0}=\mathrm{V}_{1}$ the electronic states in the leads are far from free electron-like, see F ig. 4. In particular, the transm ission


F IG . 5: (C olor online) The total transm ission as function of energy (in units of $V_{1}$ ) for the two cases $V_{0}=0$ (crosses) and $\mathrm{V}_{0}=\mathrm{V}_{1}$ (dots). In both cases $\mathrm{k}_{\mathrm{k}}=(0 ; 0)$. T he solid lines represent the analytical solution for $\mathrm{V}_{0}=0$ and the lexact" num erical solution for $V_{0}=V_{1}$.


F IG . 6: (C olor online) The total transm ission as function of energy (in units of $V_{1}$ ) for the two cases $k_{k}=(0 ; 0)$ (dots) and $\mathrm{k}_{\mathrm{k}}=(0: 47 ; 0: 21)=$ (triangles). In both cases $\mathrm{V}_{0}=\mathrm{V}_{1}$. T he solid lines represent the \exact" num erical solution.
drops to zero if the energy is inside a band gap, because there are no lead states of that energy.

The num erical calculations accurately capture the transm ission curve over a large energy range, as is show $n$ in F ig. 6. The transm ission generally increases $w$ ith energy due to the increasing number of channels, see Fig.4. Since the density of states peaks at the band edges, the transm ission peaks at the corresponding energies. The transm ission depends very much upon $k_{k}$ as can be observed in $F$ ig. .6, where the transm ission for norm al incidence, $\mathrm{k}_{\mathrm{k}}=(0 ; 0)$, can be com pared to that for $\mathrm{k}_{\mathrm{k}}=(0: 47 ; 0: 21)=\mathrm{a}$ (an arbitrary point in the B rillouin zone). The di erence betw een the two curves can be easily understood from the band structure of the leads. In particular, for $\mathrm{k}_{\mathrm{k}}=(0: 47 ; 0: 21)=$ a there are no band gaps for $\mathrm{E}>0: 14 \mathrm{~V}_{0}$.

To dem onstrate the convergence of the num erical calculations, $F$ ig. 7 show s the total transm ission as function of the sam pling density $L=W_{y}=W_{z}$ forasimple $N=1$


FIG.7: The total transm ission T as function of the grid size $\mathrm{L}=\mathrm{W}_{\mathrm{y}}=\mathrm{W}_{\mathrm{z}}$ for a simple $\mathrm{N}=1 \mathrm{FDA},{ }^{+}$' top curve, and for a $N=4$ FDA, ' 'bottom curve. The horizontal line represents the lexact" value $T=0: 132$. T he inset show s the $N=4$ curve on a ner scale for $T$.
and a high order $N=4$ FDA. The results shown are for one particular $\mathrm{k}_{\mathrm{k}}=\left(\mathrm{k}_{\mathrm{y}} ; \mathrm{k}_{\mathrm{z}}\right)=(0: 47 ; 0: 21)=$ and energy $\mathrm{E}=0: 895 \mathrm{~V}_{0}$, but the convergence at other $\mathrm{k}_{\mathrm{k}}$-points and energies is very sim ilar. T he num ber of propagating channels at this $\mathrm{k}_{\mathrm{k}}$-point and energy is tw o, but the total transm ission is only $T=0: 132$, which $m$ eans that the barrier is largely re ecting. We conclude that the accuracy of the three-dim ensional calculation depends very strongly upon the order of the FDA. For $\mathrm{N}=1$; $\mathrm{L}=15$, the transm ission is converged on a scale of $10^{2}$ only, but for $N=4$ it is converged on a scale of $10^{3}$ already for $\mathrm{L}=8$, see the inset ofF ig. 7 . A high orderFDA thus enables the use of a $m$ uch coarser realspace grid. Since the com putational costs scale w ith the num ber of real space grid points $N_{r s}=L^{3}$ as $N_{r s}^{3}=L^{9}$, this dem onstrates the strength of using a high order FDA.

> B. Sodium atom ic w ires

W e have calculated the electronic transport in sodium atom ic w ires as exam ples ofm ore com plex system s. O ur m odel of a sodium $w$ ire consists of left and right leads com posed of bulk (bcc) sodium $m$ etal term inated by a (100) surface, connected by a straight wire of sodium atom s , as is show n in F ig. 8 . The atom s in the leads are positioned according to the bcc structure ofbulk sodium, w ith the cellparam eter xed at the experim entalvalue of $7.984 \mathrm{a}_{0}{ }^{39} \mathrm{~T}$ he atom s in the w ire are xed at their (bulk) nearest neighbor distance of $6.915 \mathrm{a}_{0}$. Since geom etry relaxation at the $\mathrm{Na}(100)$ surface is very sm all, 40 and calculations using jellium electrodes have show $n$ that the conductance of a sodium $w$ ire is not very sensitive to its geom etry ${ }^{41}$ we have refrained from optim izing the geom etry. P enpendicular to the w ire we apply periodic boundary conditions using a 22 lateralsupercell, which has a lattice param eter of $15.968 \mathrm{a}_{0}$.

If DFT is used to model the electronic structure, Eq. (2) corresponds to the $K$ ohn-Sham equation. The one-


F IG . 8: (C olor online) Structure of an atom ic wire consisting of 4 sodium atom $s$ betw een tw o sodium leads term inated by (100) surfaces. T he scattering region is bounded by the vertical lines and the lateral supercell.by the horizontal lines. Bulk atom $s$ are indicated by yellow (light grey) balls and atom $s$ in the scattering region by blue (dark grey) balls, respectively.
electron potential V ( r ) in this equation is then given by the sum of the nuclear $C$ oulom b potentials or pseudopotentials, and the electronic $H$ artree and exchangecorrelation potentials. T he latter two depend upon the electronic charge density. In linear response the charge density rem ains that of the ground state, allow ing the electronic potentials to be obtained from a self-consistent ground state calculation. In these calculations w e em ploy supercells containing a slab of 13 layers to represent the bulk and surface of the leads, and a w ire of $n$ atom $s$, see Fig. 8. W e use the local density approxim ation ${ }^{42}$ and represent the ion cores of the sodium atom s by a local pseudopotential ${ }^{43} \mathrm{~T}$ he valence electronic w ave functions are expanded in a plane $w$ ave basis set w ith a kinetic energy cuto of 16 Ry . $T$ he lateralB rillouin zone is sam pled $w$ th a $8 \quad 8 k_{k}$-point grid, using a tem perature broadening w ith $\mathrm{kT}_{\mathrm{el}}=0: 1 \mathrm{eV} 44$

We want to calculate the conductance for various lengths of the atom ic $w$ ire, so for each length $n$ we perform a self-consistent supercell calculation to generate the one-electron potential. By expressing the latter in a plane w ave basis, Fourier interpolation can be used to obtain a representation on any real space grid required for the transport calculations, cf. Eq. (4). A n exam ple of the e ective potential for valence electrons of a sodium atom ic w ire is shown in Fig. 9 .

For the transport calculations we use a scattering region com prising the atom ic wire and the surface regions of the left and right leads. B oth surface regions consist of 5 atom ic layers, see F ig. 8. P eriodic boundary conditions and a 2 lateral supercell penpendicular to the wire are applied. The potential in the scattering region is extracted from the slab calculations. O utside the scattering region we assum e that the leads consist of bulk sodium . $T$ he potential for the leads and the value of the Ferm i energy are extracted from a bulk calculation. T he average bulk potential is lined up w ith the average potential in the m iddle of the supercell slab ${ }^{45} \mathrm{~W}$ e have checked that the spatial dependence of the bulk potential is virtually identical to that of the potential in the $m$ iddle of


F IG .9: (C olor online) The ective potential for valence electrons in the xy-plane of the sodium atom ic wire shown in F ig 8. M ost prom inent are the strongly repulsive core regions and the attractive valence regions of the atom $s$. T he di erence betw een the $m$ axim um and $m$ inim values of this potential is $32: 4 \mathrm{eV}$. T he Ferm i level is at $8: 5 \mathrm{eV}$ above the potentialm inim um.
the slab. This $m$ eans that the connection betw een the leads and the scattering region is sm ooth. T here are no discontinuities in the potential in the boundary regions that could cause spurious re ections.
$F$ ig 10 show s the calculated conductanœ $G\left(E_{F}\right)$ at the Ferm ilevel as a function of the length $n$ of the sodium atom ic wire. The conductance is calculated using a grid spacing along x;y and $z$ directions of $h_{x ; y ; z}=0: 67 a_{0}$ (giving $\mathrm{L}=6 ; \mathrm{W}_{\mathrm{y}}=\mathrm{W}_{\mathrm{z}}=24$ ) and a FDA of order $\mathrm{N}=4{ }^{46} \mathrm{~T}$ he $2 \quad 2$ lateralB rillouin zone is sam pled by a 1212 uniform $k_{k}-$ point grid. W th these param $e^{-}$ ters the calculated conductances have converged to well w thin $10^{3} \mathrm{G}_{0}$ (where $\mathrm{G}_{0}=\mathrm{e}^{2}=(\sim)$ ) 47 A llw ires have a conductance close to unity, except the one-atom ( $n=1$ ) w ire. T he high conductance for the one-atom w ire is fore$m$ ost due to tunneling betw een the left and right leads through vacuum. T he latter can be calculated by om itting the $w$ ire and otherw ise keeping the geom etry xed. Tunneling through vacuum leads to a conductance of 220 $G_{0}$ per 22 surface cell. V acuum tunneling decreases fast w ith the distance betw een left and right lead surfaces. At a distance corresponding to the tw o-atom wire it gives a conductance of $0.047 \mathrm{G}_{0}$; at distances corresponding to longer w ires this conductance is negligible. Subtracting these vacuum tunneling values gives the low er curve in Fig. 10 .

W ith the exception of the one-atom ic w ire, the conductances are close to unity. T his is perhaps not surprising, since $w$ ithin a tight-binding $m$ odel atom ic $w$ ires consisting of a m onovalent atom like sodium are expected to have one open channel. For perfectly transm itting contacts this would give a conductance of $1 \mathrm{G}_{0} 48 \mathrm{O}$ ur calculated conductances for $n>1$ are less than $15 \%$ sm aller than this value, dem onstrating that this transm ission is indeed very high. The conductance of the one-atom ic w ire, relative to the vacuum tunneling conductance at this distance, is signi cantly low er than unity. T he electronic structure of a single atom betw een tw o electrodes is substantially distorted from the sim ple single open chan-


F IG . 10: Top curve: conductance G ( $\mathrm{E}_{\mathrm{F}}$ ) at the Ferm i level (in units of $e^{2}=\sim$ ) of a sodium atom ic $w$ ire as a function of the number of atom $\mathrm{s} n$ in the w ire. B ottom curve: conductance of a sodium atom ic w ire relative to vacuum tunneling conductance betw een tw o electrodes w ithout w ire.
nelm odel ${ }^{8}$
On a ner scale we nd evidence of an even-odd oscillation in the conductance obtained in previous studies $8,49,50,51,52 \mathrm{~T}$ he conductance forw iresw ith n even tends to be lower than for those w th n odd. In sim ple tight-binding term s odd-num bered atom ic wires have a non-bonding level that tends to line up with the Ferm i level of the leads, which gives a high transm ission. For an even-num bered atom ic wire on the other hand the Ferm ilevel tends to fall in the gap betw een the bonding and anti-bonding levels of the wire, resulting in a low er transm ission ${ }^{53} \mathrm{~T}$ he size of the even-odd oscillation in the conductance depends of course upon the nature of the contacts betw een the atom ic w ire and the leads. G ood contacts broaden the levels of the atom ic w ire into w ide resonances, which tends to suppress the even-odd oscillation. O ur w ires have good contacts, but the even-odd oscillation rem ains distinctly visible ${ }^{54}$

> IV . SUM M ARY

W e have form ulated and im plem ented a new num erical technique for calculating electronic transport in quantum wires and tunnel junctions in the linear response regim e, starting from Landauer's scattering form alism. It is based upon a real space grid representation of the scattering problem. D ividing space into left and right ideal leads and a scattering region, the problem is solved by wave function $m$ atching ( W FM ). F irst all propagating and evanescent B loch m odes of the leads are calculated. Subsequently the states in the scattering region are forced to $m$ atch to the $B$ loch $m$ odes of the leads. $T$ his directly leads to the transm ission $m$ atrix, which contains the transm ission probability am plitudes betw een all $m$ odes of the left and right leads, and to the conductance. T he com puting costs of this algorithm scale linearly with the size of the scattering region.

It is shown that the use of a high order nite difference approxim ation for the kinetic energy operator leads to a high accuracy and e ciency. This is dem onstrated for a m odel potential by benchm arking the technique against analytical and num erically \exact" solutions. The $m$ ethod is then applied to calculate the conductance in sodium atom ic wires, where the potential in the wire and in the bulk sodium leads is obtained from self-consistent D F T calculations.

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APPENDIX A:COMPUTATIONALDETAILS

## 1. $H$ and $B m$ atrices

In th is section the $m$ atrioes $H_{i}$ and $B$, introduced in Sec.IIA, are presented explicitly. In order not to com plicate the notation the subscript i is dropped; allquantities refer to a single cell. For a w ire w ith a nite cross-section in the $y z$ plane, the $m$ atrix $H$ is real and sym $m$ etric and has the form

$$
\begin{align*}
& 0 \quad 0 \quad::: \quad 0 \quad 0 \quad::: \quad 1 \quad h_{L} \tag{A1}
\end{align*}
$$

$H$ ere $N$ is the order of the nite di erence form ula used, see E q. (3). W e assum $e$ that the $x$-ax is is in the direction of the wire. L is the num ber of grid points in the $x-$ direction of the unit cellde ned by the periodic potential.
$T$ he subm atrices $h_{n}$ and $n$ are ofdim ension $W_{y} \quad W_{z}$, which is the number of grid points in the cross section of the $w$ ire. D enoting $(k ; l)=k+(1 \quad 1) W_{y} ; k=$ $1 ;::: ; \mathrm{W}_{\mathrm{y}} ; \mathrm{l}=1 ;::: ; \mathrm{W}_{\mathrm{z}}$ as the com pound index covering the grid points in the cross section, the non-zero elem ents of these $m$ atrioes are easily derived from Eq. (4) .

$$
\begin{align*}
& \left(\mathrm{h}_{\mathrm{j}}\right)_{(\mathrm{k} ; 1) ;(\mathrm{k} ; 1)}=\mathrm{V}_{\mathrm{j} ; \mathrm{k} ; 1}\left(\mathrm{k}+\mathrm{t}_{0}^{\mathrm{y}}+\mathrm{t}_{0}^{\mathrm{z}}\right) \\
& \left(h_{j}\right)_{(k ; 1) ;(k+n ; 1)}=\quad \sum_{H} ; n \neq 0 \\
& \left(h_{j}\right)_{(k ; 1) ;\left(k ; l+n^{0}\right)}=\xi_{1}^{2} ; n^{0} \in 0 \\
& (j)_{(k ; 1) ;(k ; 1)}=t_{j}^{x} ; \tag{A2}
\end{align*}
$$

where $N \quad n ; n \quad N$ and $1 \quad k ; k+n \quad W_{j} ; 1$ lil+ $n^{0} \quad W_{z} ; 1 \quad j \quad N$. Note that in writing down these $m$ atrices $w e$ have assum ed that $N<L ; W_{y} ; W_{z}$. In practicalcalculations on realistic system $s$ this $w$ ill alw ays be the case.

Them atrix B has the sam e dim ension as H, but it is upper triangular

For a wire that is periodic in the $y z$ plane, the wave functions in Eq. (4) m ust obey B loch conditions. T hat is, $\quad j ; k+W_{y ; 1}=e^{i k_{y} a_{y}} \quad j ; k ; l$ and $\quad j ; k ; l+W_{z}=e^{i k_{z} a_{z}} \quad j ; k ; 1$, $w$ here $a_{y} ; a_{z}$ are the periods in the $y$ and $z$ directions, and $\left(k_{\mathrm{y}} ; \mathrm{k}_{\mathrm{z}}\right)=\mathrm{k}_{\mathrm{k}}$ is the B loch wave vector in the yz plane. $T$ hese $B$ loch conditions in the yz plane can be taken into account by de ning the blocks

$$
\begin{align*}
& \left(\mathrm{h}^{0}{ }_{j}\right)_{(k ; 1) ;\left(k+W_{y}+n ; l\right)}=\mathrm{H}_{1} \mathrm{e}^{i \mathrm{k}_{\mathrm{y}} \mathrm{a}_{\mathrm{y}}} ; \mathrm{n}=\mathrm{N} ;::: ; \mathrm{k} \\
& \left(h_{j}^{0}\right)_{(k ; 1) ;\left(k W_{y}+n ; 1\right)}=\quad \sum_{1}^{y} e^{i k_{y} a_{y}} ; n=W_{y} \quad k ;::: ; N \\
& \left(h_{j}^{0}\right)_{(k ; l) ;\left(k ; l+W_{z}+n^{0}\right)}=H_{1} 0 e^{i k_{z} a_{z}} ; n^{0}=N ;::: ; \quad l \\
& \left(\mathrm{~h}_{j}^{0}\right)_{(k ; 1) ;\left(k ; 1 W_{z}+n^{0}\right)}=\quad \xi_{1}^{2} 0 e^{i k_{z} a_{z}} ; \mathrm{n}^{0}=W_{z} \quad l_{i}::: ; \mathrm{N}: \tag{A4}
\end{align*}
$$

Them atrix $H\left(k_{k}\right)$, which is obtained by substituting $h_{j}$ by $h_{j}+h_{j}^{0} ; j=1 ;::: ; L$ in Eq. A I describes a w ire that is periodic in the yz planew ith solutions corresponding to a B loch vector $\mathrm{k}_{\mathrm{k}}$. This $m$ atrix is (com plex) H erm itian.

## 2. Idealw ire

For an idealw ire, which has a periodic potentialalong the wire, Eq. (7) has to be solved to nd the propagating and the evanescent waves. The precise form of the subm atrioes in Eqs. A 1) and A 3) is not im portant in the follow ing discussion. For ease of notation we only $m$ ention the dim ensions $L$ (the num ber of grid points in the $x$-direction) and $N$ (the order of the nite di erence expression) explicitly and treat the wire as quasi onedim ensional. To nd the dim ensions of the $m$ atrioes in the three-dim ensional case, one sim ply has to m ultiply the dim ensions $m$ entioned below by $W_{y} \quad W_{z}$.

Eq. (7) is a generalized eigenvalue problem of dim ension 2L. Because them atrix $B$ is singular it has a num ber of trivial solutions $=0$ and $=1$. By using a partitioning technique we w ill elim inate these trivial solutions and reduce the problem to the 2 N non-trivial solutions. The key point is to split the vectors i into two parts containing the rst L $N$ and last $N$ elem ents, respectively. The tw o parts are denoted by the subscripts 1 and
2. Splltting the $m$ atrioes $H$ and $B$ in the sam e way one gets

$$
i=\begin{align*}
& \text { i;1 }  \tag{A5}\\
& i ; 2
\end{align*} \quad ; H=\begin{array}{ll}
H_{11} & H_{12} \\
H_{21} & H_{22}
\end{array} ; B=\begin{array}{lll}
0 & B_{12} \\
0 & B_{22}
\end{array}:
$$

$N$ ote the special form of the $m$ atrix B .
This splitting allow s Eq. (7) to be w ritten in the form

$$
\begin{aligned}
& 0
\end{aligned}
$$

From this expression it is clear that the com ponent i $1 ; 1$ only enters the problem in a trivial way as i $1 ; 1=1=1 \quad{ }_{i ; 1}$. It can be elim inated by deleting the third row and colum $n$ in Eq. A6).

Furthem ore the rst row of the $m$ atrix does not depend upon the eigenvalue . W riting out the multiplication for the rst row explicitly, one nds an expression for $i ; 1$

$$
i_{i ; 1}=\left(\mathbb{E} I_{11} \quad H_{11}\right)^{1} \quad\left(\begin{array}{llll}
H_{12} & i ; 2 & B_{12} & i 1 ; 2 \tag{A7}
\end{array}\right):
$$

This can be used to elm inate $i ; 1$ from Eq. A 6 to arrive at the equation
with

$$
\begin{align*}
& A_{11}=E I_{22} \quad H_{22} \quad H_{21}\left(E I_{11} \quad H_{11}\right)^{1} H_{12} \\
& A_{12}=H_{21}\left(E I_{11} \quad H_{11}\right)^{1} B_{12} \\
& S_{11}=B_{22}^{Y} \quad B_{21}^{Y}\left(E I_{11} \quad H_{11}\right)^{1} H_{12} \\
& S_{12}=B_{21}^{Y}\left(E I_{11}\right.  \tag{A9}\\
& \left.H_{11}\right)^{1} B_{12}:
\end{align*}
$$

Eq. A 8 is a generalized eigenvalue problem of di$m$ ension 2 N that can be solved using standard num erical techniques ${ }^{55}$ In general it gives 2 N eigenvahues m and eigenvectors $u_{m}$. As mentioned in the text, som e of these solutions are non-physical, ${ }^{33,34}$ others represent extrem ely fast grow ing or decaying w aves. B oth of these classes of unw anted solutions are easily ltered out by dem anding that $1=<j j<$, where is some threshold value. W e use this criterion to select the physically relevant solutions, which are then separated into M rightgoing and $M$ left-going solutions. T hese are used to construct the $m$ atriges of E qs. (8) and (11) which contain all the inform ation required to describe the ideal w ire.

The com putational cost of solving Eq. A 8cales as $(2 \mathrm{~N})^{3}$, whereas the cost of com puting the $m$ atrices of Eq. A 9) basically scales as ( $L \quad N)^{3}$ (which is the cost of them atrix inversion involved). D epending on the relative sizes of L and N one of these tw o steps is dom inant.

## 3. F m atrices

In this section explicit expression for the $m$ atrices $F$ and $F$ are given, see Eqs. (13) and (14). Follow ing Eq. (8), we denote the propagating and evanescent m odes of the idealw ire by $u_{m} ; m=1 ;::: ; \mathrm{M}$, where $\mathrm{M}<\mathrm{N}_{\mathrm{rs}}$ and $\mathrm{N}_{\mathrm{rs}}$ is the dim ension of the vectors. For clarity of notation we om it the labels for right-and left-going m odes here. A s in Eq. (8) we form the $\mathrm{N}_{\mathrm{rs}} \quad \mathrm{M}$ matrix

The m ode vectors $u_{m}$ are in generalnon-orthogonaland we can form the $M \quad M$ (positive de nite) overlap $m$ atrix w ith elem ents

$$
\begin{equation*}
S_{\mathrm{m} n}=u_{\mathrm{m}}^{\mathrm{y}} u_{\mathrm{n}} \quad \mathrm{~h} u_{\mathrm{n}} j \mathrm{u}_{\mathrm{n}} i: \tag{A12}
\end{equation*}
$$

This allows us to construct the dual basis $\mathrm{a}_{\mathrm{m}} ; \mathrm{m}=$ 1;:::;M

$$
\begin{equation*}
\mathrm{a}_{\mathrm{m}}=\mathrm{X}_{\mathrm{n}=1}^{\mathrm{X}^{1}} \mathrm{~S}_{\mathrm{m}}{ }^{1} \mathrm{u}_{\mathrm{n}} ; \tag{A13}
\end{equation*}
$$

w ith properties

$$
\begin{equation*}
h \mathfrak{m}_{\mathrm{m}} \dot{j} \mathrm{u}_{\mathrm{n}} \mathrm{i}=\mathrm{h} \mathrm{u}_{\mathrm{m}} \dot{\mathrm{p}}_{\mathrm{n}} \dot{\mathrm{i}}=\mathrm{mn}: \tag{A14}
\end{equation*}
$$

Now de ne the M $\quad N_{r s} m$ atrix

$$
\begin{align*}
& \text { ש }=\begin{array}{llll}
\left(e_{1}\right. & e_{M} & )^{Y} \\
0 & e_{11} & ::: ~ & e_{N}
\end{array} \tag{A15}
\end{align*}
$$

$\mathscr{F}$ is called the pseudo-inverse of $U$; note that $\mathscr{F} U=I_{M}$, $w$ here $I_{M}$ is the $M \quad M$ identity $m$ atrix ${ }^{55}$

De ning the $m$ atrix

$$
\begin{equation*}
F=U \quad V ; \tag{A16}
\end{equation*}
$$

it is easy to show that it is a solution to E q. (13). F is in fact a $m$ atrix that pro jects onto the space spanned by the m odes, as is easily dem onstrated by writing Eq. A 16) as

$$
\begin{equation*}
F=\sum_{m=1}^{x^{1}} \mu_{m} i_{m h} \mathfrak{n}_{m} \dot{j} \tag{A17}
\end{equation*}
$$

$m$ aking use of Eqs. (11) and A10 A 15). In a sim ilar way a solution to Eq. (14) is form ed by

$$
\begin{align*}
\mathcal{F} & =U \quad{ }^{1} \mathbb{E} \\
& =X_{m=1}^{M} j u_{m} i_{m}^{1} h \boldsymbol{n}_{m} j: \tag{A18}
\end{align*}
$$

N ote that $=F^{1}$ only if $M=N_{r s}$, but since $M$ $\mathrm{N} \quad \mathrm{W}_{\mathrm{x}} \quad \mathrm{W}_{\mathrm{y}}<\mathrm{N}_{\mathrm{rs}}$ (see the previous section) this w ill never be the case.

## 4. Scattering problem

T he scattering problem is described by Eq. (26). It is conveniently $w$ ritten in $m$ atrix form as

w ith

$$
\begin{align*}
\mathrm{A}_{0} & =\mathrm{EI} \mathbb{P}_{0} \\
\mathrm{~A}_{\mathrm{i}} & =\mathrm{EI} \mathrm{H}_{\mathrm{i}} ; \mathrm{i}=1 ;::: ; \mathrm{S} \\
\mathrm{~A}_{\mathrm{S}+1} & =\mathrm{EI} \mathbb{P}_{\mathrm{S}+1} \\
\mathrm{C}_{0} & =\mathrm{U}_{\mathrm{L}}(+)+\mathrm{U}_{\mathrm{L}}(\mathrm{R} \\
\mathrm{C}_{\mathrm{S}+1} & =\mathrm{U}_{\mathrm{R}}(+) \mathrm{T} \\
\mathrm{D} & =\mathrm{Q}_{\mathrm{L}}(+): \tag{A20}
\end{align*}
$$

A ll the blocks A $-D$ are $N_{r s} \quad N_{r s} m$ atrioes. Eq. A 19) represents a set of linear equations, which can be solved directly using a standard algorithm . H ow ever, the di$m$ ension of this problem is $N_{\text {tot }}=N_{r s} \quad(S+2)$, which can be rather large. Since the com puting cost scales as $\mathrm{N}_{\text {tot }}^{3}$ the direct route is not very practical.

It is how ever quite straightforw ard to construct an algorithm forwhich the com puting cost scales as $N_{r s}^{3} S$, i.e. only linearly w ith the size $S$ of the scattering region. O ne has to $m$ ake optim aluse of the block tridiagonal form of the matrix in Eq. A 19). The algorithm is a block form of $G$ aussian elim ination. The rst (and most tim e consum ing) step of this algorithm is transform ing the $m$ atrix into upper block triangular form by iteration

$$
\begin{aligned}
& A_{0}^{0}=A_{0} ; D_{0}^{0}=D ; \\
& A_{i}^{0_{i}}=A_{i} \quad B_{A}^{0}{ }_{i}^{1} B^{y} \quad i=1 ;::: ; S+1:(A 21) \\
& D_{i}^{0_{i}}=B_{i}^{0}{ }_{i 1}^{1} D_{i 1}^{0_{i}}
\end{aligned}
$$

The inverse $m$ atrices $A{ }_{i}^{0}{ }_{1}^{1}$ in this algorithm are actually not needed explicitly. Instead at each step one solves the sets of linear equations

$$
\begin{equation*}
A_{i 1}^{0} B_{i}=B^{y} ; A_{i 1}^{0} \mathcal{B}_{i}=D_{i 1}^{0} ; \tag{A22}
\end{equation*}
$$

by a standard algorithm, i.e. LU decom position of $\mathrm{A}_{\mathrm{i} 1}$ follow ed by back substitution, to obtain the $m$ atrioes $\mathbb{B}_{i}$ and ${ }^{1}{ }_{i}{ }^{55} \mathrm{~T}$ his allow s the steps in E q. A 21) to be rew ritten as

$$
\begin{equation*}
A_{i}^{0}=A_{i} \quad B B_{i} ; D_{i}^{0}=B B_{i}: \tag{A23}
\end{equation*}
$$

The solution to Eq. A 19 can now be found by back substitution

$$
\begin{align*}
& C_{S+1}=A{ }_{S+1}^{01} D_{S+1}^{0} \quad O_{i+1} \quad B_{i+1} C_{i+1} \quad i=S ;::: ; 0: \\
& C_{i}=W_{i+0} \tag{A24}
\end{align*}
$$

A gain one does not need $A{ }_{S+1}^{0}$ explicitly, but like Eq. (A22) one can solve the equivalent set of linear equations. $T$ he re ection and transm ission $m$ atrioes $R$ and $T$ can be extracted using the special form of the $m$ atrioes $C_{0}$ and $C_{S+1}$, see Eq. A20.

Very often one is only interested in the transm ission $m$ atrix. In that case one only uses the rst step of the back substitution, Eq. A 24), which can be w ritten as

$$
\begin{equation*}
A_{S+1}^{0} U_{R}(+) T=D_{S+1}^{0}: \tag{A25}
\end{equation*}
$$

$T$ his is a set of linear equations for the transm ission probability am plitudes $T$, which can be solved using a standard num erical techniques 55
$T$ he tim e consum ing steps consist of solving Eq. A22), the computing costs of which scale as $N_{r s}^{3} 56$ Using Eq. A23) in Eq. A21) requires perform ing $S+1$ of such steps and subsequently solving Eq. A25 scales as $\mathrm{N}_{\text {rs }}^{3}$. $N$ ote that the full algorithm scales linearly w ith the size $S$ of the scattering region.

## 5. Velocities

In this section we give a short derivation of the expression for the velocities, Eq. (28). It is straightforw ard to show that the vectors $u_{m}$ of q . (8) are a solution of the quadratic eigenvalue equation

$$
\begin{equation*}
m(E I \quad H) u_{n}+B u_{m}+{ }_{m}^{2} B^{y} u_{m}=0: \tag{A26}
\end{equation*}
$$

This quadratic eigenvalue equation of dim ension $\mathrm{N}_{\mathrm{rs}}$ is com pletely equivalent to the linear problem ofdim ension $2 \mathrm{~N}_{\mathrm{rs}}$ of Eq . (7). If $\mathrm{u}_{\mathrm{m}}$ is a right eigenvector of Eq. A26 belonging to the eigenvalue $m$, then by com plex conjugation of this equation one show $s$ that $u_{m}^{y}$ is a left eigenvector belonging to the eigenvalue $1=\mathrm{m}$. For a propagating state $j_{m} j=1$, so $m=1=m$, which m eans that these left and right eigenvectors belong to the sam e eigenvalue.

> W e now start from

$$
m u_{m}^{Y}(E I \quad H) u_{n}+u_{m}^{Y} B u_{m}+{ }_{m}^{2} u_{m}^{Y} B^{Y} u_{m}=0 ; \text { (A 27) }
$$

and take the derivative $\mathrm{d}=\mathrm{dE}$ of this expression. A ll the term s w th $d u_{\mathrm{m}}=\mathrm{dE}$ and $d u_{\mathrm{m}}^{\mathrm{y}}=\mathrm{dE}$ drop out, because $\mathrm{u}_{\mathrm{m}}$ and $u_{m}^{y}$ obey Eq. A 26) and its complex conjugate, respectively. The rem aining term s can be collected and slightly rew ritten using Eq. A26) ; the result is

$$
\begin{align*}
& \frac{d_{m}}{d E}{ }_{m}{ }^{1} u_{m}^{Y} B u_{m} \quad m u_{m}^{Y} B^{y} u_{m}+m u_{m}^{Y} u_{m}= \\
& 2 i_{d E}^{d} I m \quad m u_{m}^{Y} B^{Y} u_{m}+{ }_{m}=0 ; \tag{A28}
\end{align*}
$$

where the last line is obtained by $m$ aking use of $m^{1}=m$ and the fact that the vectors are norm alized, $\mathrm{u}_{\mathrm{m}}^{\mathrm{m}} \mathrm{u}_{\mathrm{m}}=1$. Eq. A28 yields an expression for $d_{m}=d E$. For propagating states $m=e^{i k_{x} a_{x}}$ and thus

$$
\begin{equation*}
\frac{d k_{x}}{d E}=\frac{1}{i a_{x ~ m}} \frac{d_{m}}{d E} \tag{A29}
\end{equation*}
$$

The usual de nition of the $B$ loch velocity $V_{n}=$ $\sim^{1} \mathrm{dE}=\mathrm{dk}_{\mathrm{x}}$ and the expression for $\mathrm{d} \mathrm{m}_{\mathrm{m}}=\mathrm{dE}$ extracted from Eq. A28) then give the expression for the veloc-止 of Eq. (28).

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